Generalized contact process with two symmetric absorbing states in two dimensions

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We explore the two-dimensional generalized contact process with two absorbing states by means of large-scale Monte-Carlo simulations. In part of the phase diagram, an infinitesimal creation rate of active sites between inactive domains is sufficient to take the system from the inactive phase to the active phase. The system therefore displays two different nonequilibrium phase transitions. The critical behavior of the generic transition is compatible with the generalized voter (GV) universality class, implying that the symmetry-breaking and absorbing transitions coincide. In contrast, the transition at zero domain-boundary activation rate is not critical.

I. INTRODUCTION

Phase transitions between different nonequilibrium steady states are a topic of great current interest in statistical physics. These transitions display large-scale fluctuations and collective behavior over large distances and long times just as equilibrium phase transition. They occur, for example, in surface growth, granular flow, chemical reactions, population dynamics, and even in traffic jams [1–7].

The so-called absorbing state transitions are a particularly well-studied type of nonequilibrium phase transitions. They separate fluctuating (active) steady states from absorbing (inactive) states where fluctuations stop completely. Generically, absorbing state transitions are in the directed percolation (DP) [8] universality class; Janssen and Grassberger [9, 10] conjectured that all absorbing state transitions with a scalar order parameter and short-range interactions belong to this class as long as there are no extra symmetries or conservation laws. This conjecture has been confirmed in countless theoretical and computer simulation studies. Experimental verifications were found in ferrofluidic spikes [11] and in the transition between two turbulent states in a liquid crystal [12].

In recent years, significant attention has focused on absorbing state transitions in universality classes different from DP that can occur if the system features additional symmetries or conservation laws. In 1997, Hinrichsen [13] suggested several nonequilibrium stochastic lattice models with $n \geq 2$ absorbing states. In the case of two symmetric absorbing states ($n = 2$), he found the critical exponents to be different from the DP values. The corresponding universality class has been given several different names in the literature such as the Z_2-symmetric directed percolation class (DP2) or the directed Ising (DI) class. If the symmetry between the two absorbing states is broken, the critical behavior reverts back to DP.

Recently, we revisited [14] one of the stochastic lattice models introduced in Ref. [13], *viz.*, the generalized contact process with two absorbing states in one space dimension. By employing large-scale Monte-Carlo simulations, we found a rich phase diagram featuring two

different nonequilibrium phase transitions separated by a special point that shares some characteristics with a multicritical point. The generic transition occurs at nonzero values of the infection, healing and domain-boundary activation rates. It belongs to the above-mentioned DP2 or DI universality class which in one dimension coincides [4] with the parity-conserving (PC) class [15] (occurring, e.g., in the branching-annihilating random walk with an even number of offspring (BARWE) [16]). In addition, we found an unusual line of phase transitions at zero domain-boundary activation rate which turned out to be non-critical.

Here, we consider the generalized contact process with two symmetric absorbing states in *two* space dimensions. The purpose of this paper is twofold. First, we wish to investigate whether the two-dimensional generalized contact process also displays the above-mentioned rich phase diagram having two nonequilibrium phase transitions. Second, we wish to study the critical behavior of these transitions and their universality. According to a conjecture by Dornic *et al.* [17], transitions with Z_2 symmetry and no bulk fluctuations (i.e., transitions with two symmetric absorbing states) should be in the generalized voter (GV) universality class for which the upper critical dimension is exactly two. Alternatively, the transition could split into a symmetry-breaking Ising transition and a DP transition [18, 19]. To address these questions, we perform large-scale Monte-Carlo simulations.

Our paper is organized as follows. We introduce the generalized contact process with several absorbing states in Sec. II. Sec. III is devoted to the results and interpretation of our Monte-Carlo simulations. We conclude in Sec. IV.

II. GENERALIZED CONTACT PROCESS WITH SEVERAL ABSORBING STATES

We first define the simple contact process [20], one of the prototypical models in the DP universality class. Each site **r** of a d-dimensional hypercubic lattice can be in one of two states, either A, the active (infected) state or I, the inactive (healthy) state. During the time evolution

of the contact process, active sites infect their nearest neighbors, or they heal (become inactive) spontaneously. More rigorously, the contact process is a continuous-time Markov process during which active sites become inactive at a rate μ, while inactive sites turn active at a rate $\lambda m/(2d)$ where m is the number of active nearest neighbor sites. The healing rate μ and the infection rate λ are external parameters.

The long-time state of the contact process is determined by the ratio of these two rates. If $\mu \gg \lambda$, healing occurs much more often than infection. Thus, all infected sites will eventually become inactive, and the absorbing state without any active sites is the only steady state. Consequently the system is in the inactive phase for $\mu \gg \lambda$. In the opposite limit, $\lambda \gg \mu$, the infection survives for infinite times, i.e., there is a steady state with a nonzero density of active sites. This is the active phase. These two phases are separated by a nonequilibrium phase transition in the DP universality class occurring at some critical value of the ratio λ/μ.

Following Hinrichsen [13], we now generalize the contact process to n absorbing states. Each lattice site can now be in one of $n + 1$ states, the active state A or one of the n different inactive states I_k ($k = 1 \ldots n$). k is sometimes referred to as the "color" index. The Markov dynamics of the generalized contact process is defined via the following transition rates for pairs of nearest-neighbor sites,

$$w(\text{AA} \to \text{AI}_k) = w(\text{AA} \to \text{I}_k\text{A}) = \bar{\mu}/n , \qquad (1)$$

$$w(\text{AI}_k \to \text{I}_k\text{I}_k) = w(\text{I}_k\text{A} \to \text{I}_k\text{I}_k) = \mu_k , \qquad (2)$$

$$w(\text{AI}_k \to \text{AA}) = w(\text{I}_k\text{A} \to \text{AA}) = \lambda , \qquad (3)$$

$$w(\text{I}_k\text{I}_l \to \text{I}_k\text{A}) = w(\text{I}_k\text{I}_l \to \text{AI}_l) = \sigma , \qquad (4)$$

with $k, l = 1 \ldots n$ and $k \neq l$. All other transition rates vanish. We are mostly interested in the fully symmetric case, $\mu_k \equiv \mu$ for all k. For $n = 1$ and $\bar{\mu} = \mu$, the so defined generalized contact process coincides with the simple contact process discussed above. One of the rates $\bar{\mu}, \mu, \lambda$, and σ can be set to unity without loss of generality, thereby fixing the unit of time. We choose $\lambda = 1$ in the following. Moreover, to keep the parameter space manageable, we focus on the case $\bar{\mu} = \mu$ [21].

The rate (4) is responsible for the new physics in the generalized contact process. It prevents inactive domains of different color (different k) to stick together indefinitely. By creating active sites at the domain wall, the two domains can separate. Thus, the rate (4) allows the domain walls to move through space. We emphasize that without the process (4), i.e., for $\sigma = 0$, the color of the inactive sites becomes unimportant, and all I_k can be identified. Consequently, for $\sigma = 0$, the dynamics of the generalized contact process reduces to that of the simple contact process for all values of n. In the main part of this paper, we shall focus on the case of $n = 2$ inactive states.

Before we turn to our Monte-Carlo simulations of the two-dimensional generalized contact process, let us briefly summarize the simulation results in one dimension [14] for comparison. For $\sigma = 0$, i.e., in the absence of the boundary activation process (4), the system undergoes an absorbing state transition at a healing rate $\mu = \mu_c^{cp} \approx 0.303$, which agrees with the critical healing rate of the simple contact process. In agreement with the general arguments above, this transition is in the DP universality class. For healing rates between μ_c^{cp} and $\mu^* \approx 0.552$, the system is inactive if $\sigma = 0$ but an infinitesimal nonzero σ takes it to the active phase. Finally, for $\mu > \mu^*$, the transition occurs at a finite nonzero value of σ. The one-dimensional generalized contact process with two inactive states thus has two lines of phase transitions, (i) the generic transition occurring at $\mu > \mu^*$ and $\sigma = \sigma_c(\mu) > 0$ and (ii) the transition occurring for $\mu_c^{cp} < \mu < \mu^*$ as σ approaches zero.

III. MONTE-CARLO SIMULATIONS

A. Method and phase diagram

In order to address the two main problems raised in the introduction, *viz*, the phase diagram of the two-dimensional generalized contact process with two inactive states and the critical behavior of its phase transitions, we performed two types of large-scale Monte Carlo simulations, (i) decay runs and (ii) spreading runs. Decay runs start from a completely active lattice; we measure the time evolution of the density $\rho(t)$ of active sites as well as the densities $\rho_1(t)$ and $\rho_2(t)$ of sites in inactive states I_1 and I_2, respectively. Spreading simulations start from a single active (seed) site embedded in a system of sites in state I_1. Here we monitor the survival probability $P_s(t)$, the number of sites in the active cloud $N_s(t)$ and the mean-square radius of this cloud, $R^2(t)$.

In both types of runs, the simulation is a sequence of individual events. In each event, a pair of nearest-neighbor sites is randomly selected from the active region. For the spreading simulations, the active region initially consists of the seed site and its neighbors; it is updated in the course of the simulation according to the actual size of the active cluster. For the decay runs, the active region comprises the entire sample. The selected pair than undergoes one of the possible transitions according to eqs. (1) to (4) with probability τw. Here the time step τ is a constant which we fix at $1/2$. The time increment associated with the event is τ/N_{pair} where N_{pair} is the number of nearest-neighbor pairs in the active region.

Using this procedure, we investigated the parameter region $0.5 \leq \mu \leq 1.2$ and $0 \leq \sigma \leq 1$. We simulated samples with sizes up to 20000×20000 sites for times up to $t_{max} = 3 \times 10^6$. The $\sigma - \mu$ phase diagram that emerged from these calculations is shown in in Fig. 1.

In many respects, it is similar to the phase diagram of the one-dimensional generalized contact process [14]. In the absence of the domain-boundary activation process (i.e., for $\sigma = 0$), the transition from the active phase to
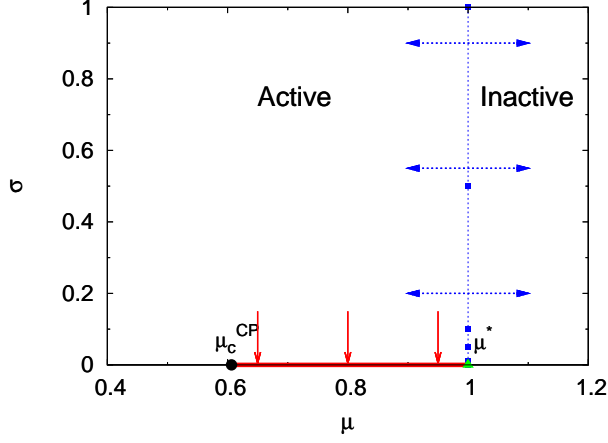
FIG. 1. (Color online) Phase diagram of the two-dimensional generalized contact process with two inactive states as function of the healing rate μ and the domain-boundary activation rate σ. For $\mu < \mu_c^{cp} = 0.6066$, the system is in the active phase for any σ. For $\mu_c^{cp} < \mu < \mu^* = 1.0000$, the system is inactive at $\sigma = 0$ (thick solid red line), but an infinitesimal σ takes it to the active phase. For $\mu > \mu^*$, the system is inactive for any σ.
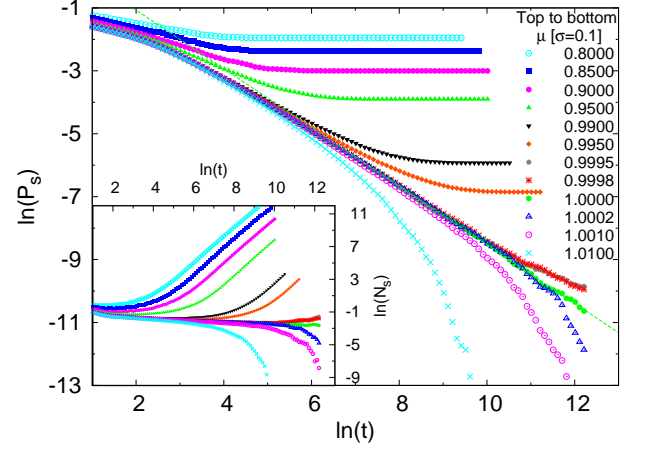

FIG. 2. (Color online) Spreading simulations at $\sigma = 0.1$ for several μ close to the phase boundary. Main panel: Survival probability P_s as a function of time t. Inset: Number N_s of active sites as a function of time t. The data close to criticality are averages over 10^6 runs on a 4000×4000 system, smaller numbers of runs were used away from criticality.

the inactive phase occurs at a healing rate of $\mu = \mu_c^{cp} = 0.6066(2)$ which agrees well with the critical point of the simple contact process (see, e.g., Refs. [22, 23]). For healing rates in the interval $\mu_c^{cp} < \mu < \mu^* = 1.0000(2)$, the generalized contact process is inactive at $\sigma = 0$, but an infinitesimal nonzero σ takes it to the active phase. Thus, we find a line a phase transitions at $\mu_c^{cp} < \mu < \mu^*$ and $\sigma = 0$. In addition to this line of $\sigma = 0$ absorbing state transitions, we also find a line of generic (nonzero σ and μ) transitions. In contrast to one space dimension, this line is exactly "vertical" within our accuracy, i.e., the critical healing rate $\mu_c = 1.0000(2)$ does *not* depend on σ for all $\sigma > 0$. We note in passing that our critical healing rate is in agreement with the estimate $\mu_c \approx 0.99(1)$ obtained in Ref. [13] for $\sigma = 1$.

In the following subsections we shall discuss in detail the properties of both phase transition lines as well as special point $(\mu^*, 0)$ that separates them.

B. Generic transition

In order to identify the generic transition and to study its critical behavior, we performed sets of spreading simulations at constant domain-boundary activation rate $\sigma = 0.01, 0.05, 0.1, 0.5$ and 1. For each σ, we have varied the healing rate μ from 0.8 to 1.1. Figure 2 shows the resulting time evolution of the survival probability P_s and the number of sites in the active cloud $N_s(t)$ for $\sigma = 0.1$ and several μ. The data indicate a critical healing rate of $\mu_c = 1.0000(2)$ for this σ value. Analogous simulations for $\sigma = 0.01, 0.05, 0.5$ and 1 yielded, somewhat surprisingly, exactly the same critical healing rate. We thus
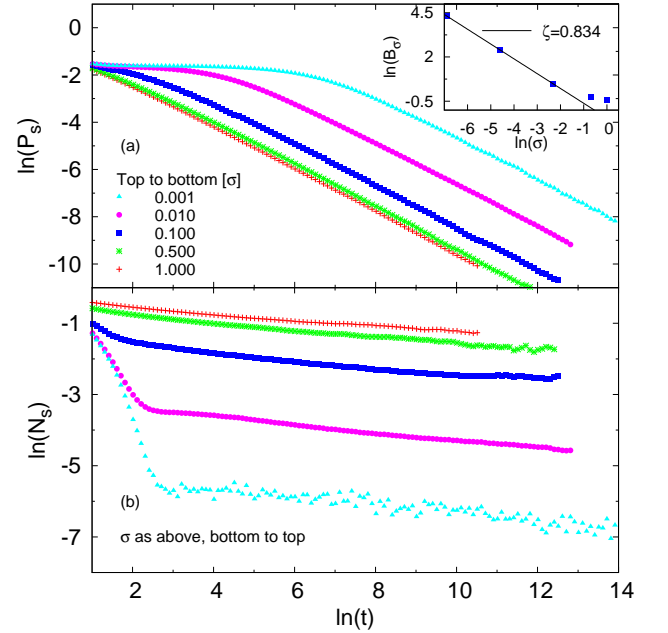

FIG. 3. (Color online) Survival probability P_s and number of active sites N_s as functions of t for several points located on the generic phase boundary $\mu = 1.0000$ (2×10^6 to 10^7 runs used). Inset: prefactor B_σ vs. σ. The straight line is a fit to a power-law $B_\sigma \sim \sigma^{-\zeta}$.

conclude that in the two-dimensional generalized contact process, the critical healing rate μ_c is independent of σ for all $\sigma > 0$.

Figure 3 shows the survival probability P_s and number N_s of active sites as functions of time for all the respective critical points. In log-log representation, the long-time
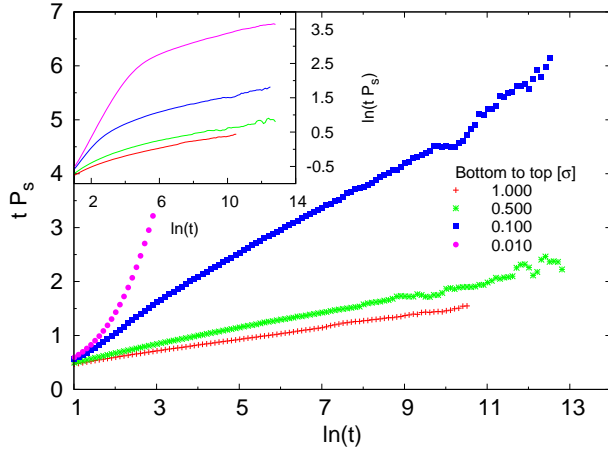
FIG. 4. (Color online) Survival probability $P_s(t)$ for several points located on the generic phase boundary plotted as $t\,P_s$ vs. $\ln(t)$. Straight lines correspond to mean-field behavior with logarithmic corrections. Inset: Same data plotted as $\ln(t\,P_s)$ vs. $\ln(t)$. Straight lines represent pure power laws.
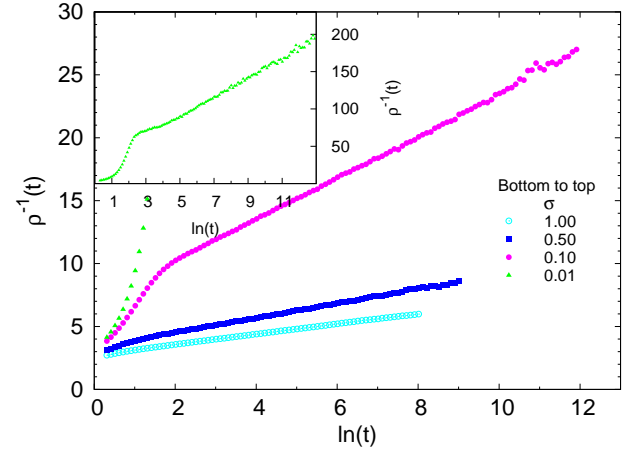

FIG. 5. (Color online) Density of active sites plotted as $\rho^{-1}(t)$ vs. $\ln(t)$ for several points located on the generic phase boundary. The data are averages over 100 runs with system size 500 × 500. The curve for $\sigma = 0.01$ is shown in the inset because its density values are much smaller than those of the other curves.

parts of the N_s and P_s curves for different σ are perfectly parallel within their statistical errors, i.e., they differ only by constant factors, confirming that the critical behavior of the generic transition is universal. Fits of the long-time behavior to the pure power laws $P_s = B_\sigma t^{-\delta}$ and $N_s = C_\sigma t^\Theta$ give estimates of $\delta = 0.900(15)$ and $\Theta = -0.100(25)$. These values are very close to the mean-field values $\delta_{MF} = 1$ and $\Theta_{MF} = 0$. According to the conjecture by Dornic *et al.* [17], the generic transition should be in the GV universality class. Because the upper critical dimension of this universality class is exactly two, this conjecture corresponds to mean-field behavior with logarithmic corrections.

To test this prediction we compare in Fig. 4 plots of $\ln(t\,P_s)$ vs. $\ln(t)$ (straight lines corresponds to power laws) and $t\,P_s$ vs. $\ln(t)$ (straight lines correspond to logarithmic behavior). Although both functional forms describe the long-time data reasonably well, the curves in the $\ln(t\,P_s)$ vs. $\ln(t)$ plot show a systematic downward curvature. Moreover, the semi-logarithmic plot, $t\,P_s$ vs. $\ln(t)$, leads to straight lines over a longer time interval which we take as evidence for GV critical behavior. We performed an analogous analysis for number of active sites N_s. Again, both a simple power law and mean-field behavior with logarithmic corrections describe the data reasonably well, with the quality of fits being somewhat higher for the latter case. We also measured (not shown) the mean-square radius $R^2(t)$ of the active cloud as a function of time. A pure power-law fit of its long time behavior, $R^2(t) \sim t^{2/z}$, gives $2/z = 0.97(4)$ ($z = 2.06(8)$). The data can be described equally well by mean-field behavior $R^2(t) \sim t$ with logarithmic corrections.

In addition to the spreading runs, we also performed density decay runs at the generic phase boundary. The resulting density of active sites ρ as a function of time can be fitted with a pure power law $\rho(t) \sim t^{-\alpha}$ giv-

ing a very small value of $\alpha = 0.080(4)$. A better fit is achieved with the simple logarithmic time dependence $\rho(t) \sim 1/\ln(t/t_0)$ (with t_0 a microscopic time scale) expected for the GV universality class. This type of behavior is demonstrated in Fig. 5.

In summary, although all our results for the generic transition can be fitted both by pure power laws and by mean-field behavior with logarithmic corrections, the latter functional forms yield fits of somewhat higher quality. We also note that the critical exponents resulting from the pure power-law fits approximately fulfill the hyperscaling relation $\Theta - d/z = -\alpha - \delta$. However, the agreement is not very good (in particular, it is significantly worse than in one dimension [14]), indicating that the measured pure power-laws are not the true asymptotic behavior. Our results thus support the conjecture that the generic transition of the two-dimensional generalized contact process with two inactive states is in the GV universality class.

C. Transition at $\sigma = 0$

After addressing the generic transition, we now discuss in more detail the line of phase transitions occurring at $\sigma = 0$ and $\mu_c^{cp} < \mu < \mu^*$. To study these transitions, we carried out several sets of simulations for fixed healing rate μ and several σ values approaching $\sigma = 0$.

We start by discussing the density decay runs. Figure 6 shows the stationary density ρ_{st} of active sites (reached at long times) as function of σ for several values of the healing rate μ. The figure shows that the stationary density depends linearly on σ for all healing rates in the interval $\mu_c^{cp} < \mu < \mu^*$, i.e., $\rho_{st} = B_\mu \sigma^\omega$ with $\omega = 1$ and B_μ being a μ-dependent constant. We also analyzed how
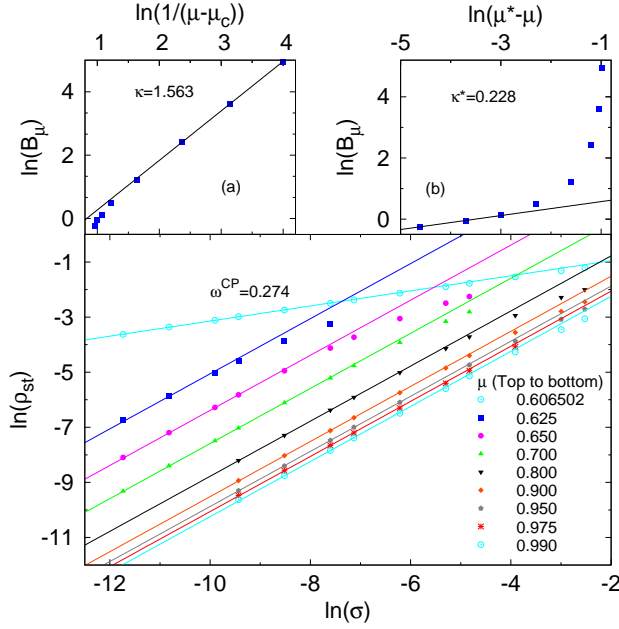
FIG. 6. (Color online) Density decay simulations. Main panel: stationary density ρ_{st} as a function of the boundary rate σ for various healing rates μ. For $\mu_c^{cp} < \mu < \mu^*$, the solid lines are fits of the low-σ behavior to $\rho_{st} = B_\mu \sigma$. At the simple contact process critical point, $\mu = \mu_c^{cp} = 0.6066$, we fit to the power-law $\rho_{st} \sim \sigma^{\omega_{cp}}$ which gives an exponent of $\omega_{cp} = 0.274(5)$. The data are averages over 300 to 600 runs with system sizes 100×100. Inset a: prefactor B_μ of the linear σ dependence as a function of $\mu - \mu_c^{cp}$. A fit to a power law gives $B_\mu \sim (\mu - \mu_c^{cp})^{-\kappa}$ with $\kappa = 1.56(5)$. Inset b: prefactor B_μ as a function of $\mu^* - \mu$. A fit to a power law gives $B_\mu \sim (\mu^* - \mu)^{\kappa^*}$ with $\kappa^* \approx 0.23$.

the prefactor B_μ of this mean-field-like behavior depends on the distances from the simple contact process critical point and from the special point at $\mu = \mu^*$ and $\sigma = 0$. As inset (a) of Fig. 6 shows, B_μ diverges as $(\mu - \mu_c^{cp})^{-\kappa}$ with $\kappa = 1.56(5)$. According to inset (b), it vanishes as $(\mu^* - \mu)^{\kappa^*}$ with $\kappa^* \approx 0.23$ when approaching μ^*.

At the critical healing rate μ_c^{cp} of the simple contact process, the stationary density displays a weaker σ-dependence. A fit to a power-law $\rho_{st} \sim \sigma^{\omega_{cp}}$ gives an exponent value of $\omega_{cp} = 0.274(5)$.

Let us now compare these results with the behavior of spreading simulations in the same parameter region. Figure 7 shows the survival probability $P_s(t)$ and the number of active sites $N_s(t)$ for a fixed healing rate of $\mu = 0.8$ and several values of the boundary rate σ. After an initial decay, the number of active sites grows with time for all σ values, establishing that the system is in the active phase for all $\sigma > 0$. In agreement with this, the survival probability approaches a nonzero constant in the long-time limit. Remarkably, this stationary survival probability does *not* approach zero with vanishing σ. Instead, it approaches a σ-independent constant. We performed similar sets of simulations at other values of μ in the range $\mu_c^{cp} < \mu < \mu^*$, with analogous results.
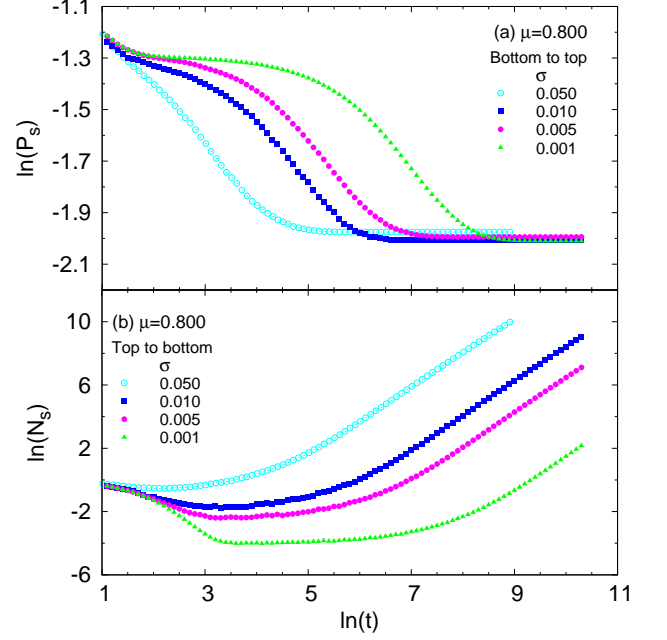

FIG. 7. (Color online) Spreading simulations: Survival probability P_s and number of active sites N_s as functions of time t for a fixed healing rate of $\mu = 0.8$ and several σ. The data are averages over 2000 to 10000 runs on a 4000×4000 system.

We thus conclude that the behavior at the $\sigma = 0$ transition of the two-dimensional generalized contact process is very similar to the one-dimensional case. It can be understood in terms of the domain-wall motion as follows [14]. The relevant long-time degrees of freedom at $\mu > \mu_c^{cp}$ and $\sigma \ll 1$ are the domain walls between I_1 and I_2 domains. These walls can hop, branch and annihilate. The crucial observation is that the rates which control the domain wall dynamics are all proportional to σ for $\sigma \ll 1$, implying that their ratios are σ-independent. Consequently, the stationary state of the domain walls does not depend on σ for $\sigma \ll 1$. This explains why the survival probability P_s saturates at a nonzero, σ-independent value in Fig. 7. It also explains the σ-dependence of the stationary density ρ_{st} because active sites are created mostly at the domain walls at rate σ. Therefore, their stationary density is proportional to both σ and the stationary domain wall density ρ_{dw}, i.e., $\rho_{st} \sim \sigma \rho_{dw}$, in agreement with Fig. 6. Based on this argument, the exponent κ^* in inset (b) of Fig. 6 should be identical to the exponent β of the generic transition line [14], which vanishes in mean-field theory. Our value, $\kappa^* \approx 0.23$ is thus somewhat too high which we attribute to it not representing the asymptotic behavior, in agreement with the significant curvature of the data in inset (b) of Fig. 6.

Just as in one dimension, the phase transition line at $\sigma = 0$ and $\mu_c^{cp} < \mu < \mu^*$ is thus not a true critical line. It only appears critical because the stationary density ρ_{st} (trivially) vanishes with σ. Correspondingly, the time

evolution right on the transition line $\sigma = 0$ does not display critical power laws. This also implies that the point $(\mu, \sigma) = (\mu^*, 0)$ is not a multicritical point, but a simple critical point in the same universality class as the generic transition.

D. Scaling of ρ_{st} at the contact process critical point $(\mu_c^{cp}, 0)$

The behavior of the stationary density of active sites ρ_{st} close to the simple contact process critical point at $\mu = \mu_c^{cp}$ and $\sigma = 0$ can be understood in terms of a phenomenological scaling theory. We assume the homogeneity relation

$$\rho_{st}(\Delta\mu, \sigma) = b^{\beta_{cp}/\nu_{cp}^\perp} \rho_{st}(\Delta\mu \, b^{-1/\nu_{cp}^\perp}, \sigma b^{-y_{cp}}) \quad (5)$$

where $\Delta\mu = \mu - \mu_c^{cp}$, and b is an arbitrary scale factor. $\beta_{cp} = 0.584$ and $\nu_{cp}^\perp = 0.734$ are the usual order parameter and correlation length exponents of the two-dimensional contact process [22, 23], and y_{cp} denotes the scale dimension of σ at this critical point. Setting $b = \sigma^{1/y_{cp}}$ gives rise to the scaling form

$$\rho_{st}(\Delta\mu, \sigma) = \sigma^{\beta_{cp}/(\nu_{cp}^\perp y_{cp})} X\left(\Delta\mu \, \sigma^{-1/(\nu_{cp}^\perp y_{cp})}\right) \quad (6)$$

where X is a scaling function. At criticality, $\Delta\mu = 0$, this leads to $\rho_{st}(0, \sigma) \sim \sigma^{\beta_{cp}/(\nu_{cp}^\perp y_{cp})}$ (using $X(0) = $ const.). Thus, $\omega_{cp} = \beta_{cp}/(\nu_{cp}^\perp y_{cp})$. For $\sigma \to 0$ at nonzero $\Delta\mu$, we need the large-argument limit of the scaling function X. On the active side of the critical point, $\Delta\mu < 0$, the scaling function behaves as $X(x) \sim |x|^{\beta_{cp}}$ to reproduce the correct critical behavior of the density, $\rho_{st} \sim |\mu - \mu_c^{cp}|^{\beta_{cp}}$.

On the inactive side of the critical point, i.e., for $\Delta\mu > 0$ and $\sigma \to 0$, we assume the scaling function to behave as $X(x) \sim x^{-\kappa}$. We thus obtain $\rho_{st} \sim (\Delta\mu)^{-\kappa} \sigma^\omega$ (just as observed in Fig. 6) with $\omega = (\beta_{cp} + \kappa)/(\nu_{cp}^\perp y_{cp})$. As a result of our scaling theory, the exponents ω, ω_{cp} and κ are not independent, they need to fulfill the relation $\omega_{cp}(\beta_{cp} + \kappa) = \beta_{cp}\omega$. Our numerical values, $\omega = 1$, $\omega_{cp} = 0.274$ and $\kappa = 1.56$ fulfill this relation in very good approximation, indicating that they represent asymptotic exponents and validating the homogeneity relation (5). The resulting value for the scale dimension y_{cp} of σ at the simple contact process critical point is $y_{cp} = 2.9(1)$.

IV. CONCLUSIONS

To summarize, we investigated the two-dimensional generalized contact process with two inactive states by means of large-scale Monte-Carlo simulations. Its global phase diagram is very similar to that of the corresponding one-dimensional model. In particular, the generic ($\sigma > 0$) phase boundary between the active and inactive phases does not continuously connect to the critical point of the $\sigma = 0$ problem, i.e., the critical point

$(\mu_c^{cp}, 0)$ of the simple contact process. Instead, it terminates at a separate end point $(\mu^*, 0)$ on the μ axis. As a result, the two-dimensional generalized contact process has two nonequilibrium phase transitions. In addition to the generic transition occurring for $\sigma > 0$, there is a line of transitions at $\sigma = 0$ and $\mu_c^{cp} < \mu < \mu^*$. We note that there is one interesting difference between the phase diagrams in one and two dimensions. In one dimension, the critical healing rate μ_c increases with increasing boundary rate σ. In contrast, the results of this paper show that the critical healing rate in two dimensions is completely independent of σ. Moreover, its value seems to be equal to unity (i.e., equal to that of the infection rate λ). The reason for this peculiar behavior is presently an open question.

To determine the critical behavior of the generic transition, we performed simulations at and close to several points on the generic ($\sigma > 0$) phase boundary. We found the same critical behavior for all of these points, i.e, it is universal. Our data can be fitted reasonably well with pure power laws, giving the exponents $\Theta = -0.100(25)$, $\delta = 0.900(15)$, $\alpha = 0.080(4)$, and $z = 2.06(8)$. However, fits of equal and sometimes even better quality over longer ranges of time can be obtained by fitting to mean-field critical behavior, $\Theta = 0$, $\delta = 1$, $\alpha = 0$, and $z = 2$ with logarithmic corrections. Our results thus support the conjecture [17] that the critical behavior of the two-dimensional generalized contact process is right at its upper critical dimensions. (This implies that the DP2 class in two dimensions coincides with the GV class.). We also note that our simulations showed no indications of the transition being split into a symmetry-breaking transition and a separate DP transition as found in some absorbing-state Potts models [18].

As in one space dimension, the line of transitions at $\sigma = 0$ and $\mu_c^{cp} < \mu < \mu^*$ is not a critical line. The survival probability P_s remains finite when approaching this line. The density ρ of active sites vanishes, but simply because the domain-boundary activation rate σ vanishes. The behavior in the vicinity of the transition line is controlled by the dynamics of the I_1-I_2 domain walls which is not critical for $\mu_c^{cp} < \mu < \mu^*$.

Crossovers between various universality classes of absorbing state transitions in *one dimension* have been investigated by several authors [24–27]. Some of the scenarios lead to conventional crossover scaling (of the type $\sigma_c \sim (\mu - \mu_c^{cp})^{1/\phi}$). Park and Park [25] found a discontinuous jump in the phase boundary along the so-called excitatory route from infinitely many absorbing states to a single absorbing state. There also is some similarity between our mechanism and the so-called channel route [26] from the PC universality class to the DP class which involves an infinite number of absorbing states characterized by an auxiliary density (which is density of I_1-I_2 domain walls in one-dimensional the generalized contact process [14]). To the best of our knowledge, a similarly systematic investigation of crossovers between absorbing state universality classes in two space dimensions has not

yet been performed.

As our results suggest that the two-dimensional generalized contact process is right at the upper critical dimensions, the critical behavior of its (generic) phase transition in dimensions $d > 2$ should be governed by mean-field theory.

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